

N-channel TrenchMOS logic level FET Rev. 07 — 30 January 2009

Product data sheet

Product profile 1.

1.1 General description

Logic level N-channel enhancement mode Field-Effect Transistor (FET) in a plastic package using TrenchMOS technology. This product is designed and qualified for use in computing, communications, consumer and industrial applications only.

1.2 Features and benefits

- Low conduction losses due to low on-state resistance
- Suitable for logic level gate drive sources

General purpose switching

1.3 Applications

- DC-to-DC convertors
- 1.4 Quick reference data

Table 1.	Quick reference					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{DS}	drain-source voltage	T _j ≥ 25 °C; T _j ≤ 175 °C	-	-	25	V
I _D	drain current	$T_{mb} = 25 \text{ °C}; V_{GS} = 10 \text{ V}$	-	-	66	А
P _{tot}	total power dissipation	T _{mb} = 25 °C; see <u>Figure 2</u>	-	-	93	W
Dynamic	characteristics					
Q _{GD}	gate-drain charge	$V_{GS} = 5 \text{ V}; I_D = 50 \text{ A};$ $V_{DS} = 15 \text{ V}; T_j = 25 \text{ °C};$ see <u>Figure 11</u>	-	3.6	-	nC
Static ch	aracteristics					
R _{DSon}	drain-source on-state resistance	$V_{GS} = 10 \text{ V}; I_D = 25 \text{ A};$ $T_j = 25 \text{ °C}; \text{ see } Figure 9;$ see Figure 10	-	9.1	10.5	mΩ

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2. Pinning information

Table 2.	Pinning	information						
Pin	Symbol	Description		Simplified outline	Graphic symbol			
1	G	gate			_			
2	D	drain	[1]	mb				
3	S	source						
mb	D	mounting base; connected to drain			mbb076 S			
				SOT404 (D2PAK)				

[1] It is not possible to make a connection to pin 2.

3. Ordering information

Table 3.Ordering information

Type number	Package		
	Name	Description	Version
PHB66NQ03LT	D2PAK	plastic single-ended surface-mounted package (D2PAK); 3 leads (one lead cropped)	SOT404

4. Limiting values

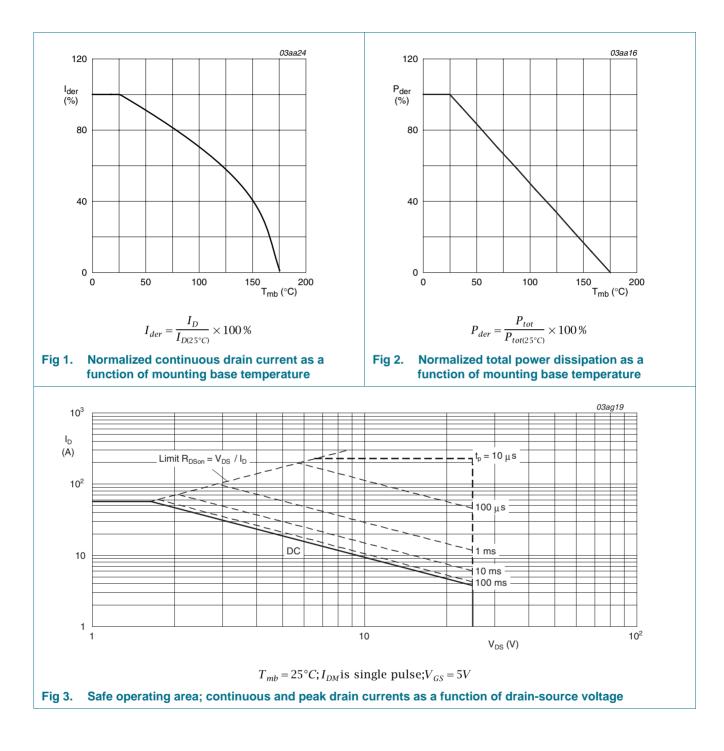
Table 4.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{DS}	drain-source voltage	T _j ≥ 25 °C; T _j ≤ 175 °C	-	25	V
V _{DGR}	drain-gate voltage	$T_j \ge 25 \text{ °C}; T_j \le 175 \text{ °C}; R_{GS} = 20 \text{ k}\Omega$	-	25	V
V _{GS}	gate-source voltage		-20	20	V
I _D	drain current	V _{GS} = 10 V; T _{mb} = 100 °C	-	45	А
		$V_{GS} = 5 \text{ V}; T_{mb} = 100 \text{ °C}; \text{ see } \frac{\text{Figure 1}}{100 \text{ C}}$	-	40	А
		V _{GS} = 5 V; T _{mb} = 25 °C; see <u>Figure 1</u> ; see <u>Figure 3</u>	-	57	А
		V _{GS} = 10 V; T _{mb} = 25 °C	-	66	А
I _{DM}	peak drain current	$t_p \le 10 \ \mu s$; pulsed; $T_{mb} = 25 \ ^{\circ}C$; see Figure 3	-	228	А
P _{tot}	total power dissipation	T _{mb} = 25 °C; see <u>Figure 2</u>	-	93	W
T _{stg}	storage temperature		-55	175	°C
Tj	junction temperature		-55	175	°C
Source-di	ain diode				
I _S	source current	T _{mb} = 25 °C	-	57	А
I _{SM}	peak source current	$t_p \le 10 \ \mu s$; pulsed; $T_{mb} = 25 \ ^{\circ}C$	-	228	А
Avalanch	e ruggedness				
E _{DS(AL)S}	non-repetitive drain-source avalanche energy	V_{GS} = 10 V; $T_{j(init)}$ = 25 °C; I_D = 43 A; V_{sup} ≤ 25 V; unclamped; t_p = 0.15 ms; R_{GS} = 50 Ω	-	90	mJ

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5. Thermal characteristics

Table 5.	Thermal characteristics	i				
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance from junction to ambient	mounted on a printed-circuit board; minimum footprint; vertical in still air	-	50	-	K/W
R _{th(j-mb)}	thermal resistance from junction to mounting base	see Figure 4	-	-	1.6	K/W

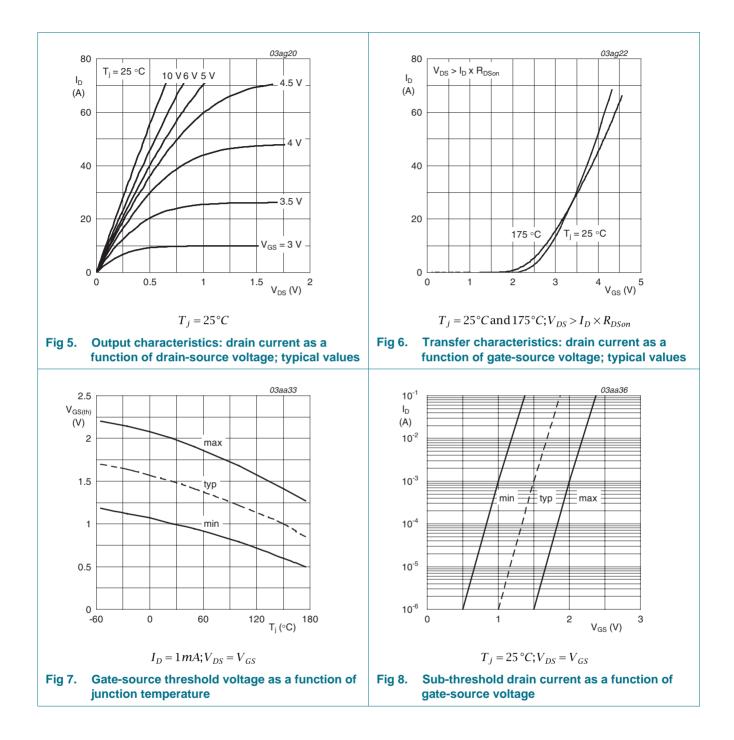


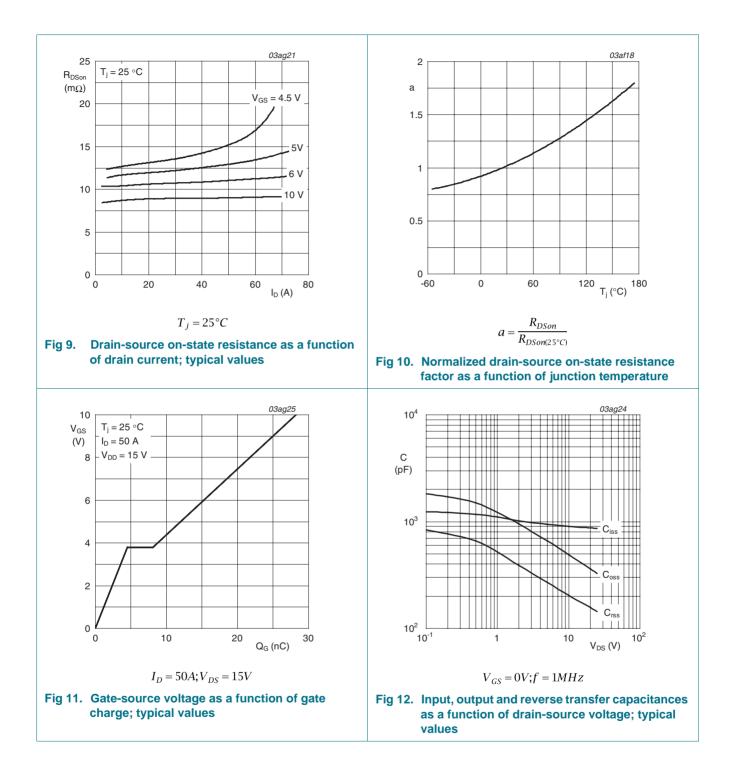
6. Characteristics

Table 6.	Characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static ch	aracteristics					
V _{(BR)DSS}	drain-source	I_D = 250 µA; V_{GS} = 0 V; T_j = -55 °C	22	-	-	V
	breakdown voltage	$I_D = 250 \ \mu A; \ V_{GS} = 0 \ V; \ T_j = 25 \ ^\circ C$	25	-	-	V
$V_{\text{GS(th)}}$	gate-source threshold voltage	$I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = -55 \text{ °C};$ see <u>Figure 7</u> ; see <u>Figure 8</u>	-	-	2.2	V
		$I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = 175 \text{ °C};$ see <u>Figure 7</u> ; see <u>Figure 8</u>	0.5	-	-	V
		$I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = 25 \text{ °C};$ see <u>Figure 7</u> ; see <u>Figure 8</u>	1	1.5	2	V
I _{DSS}	drain leakage current	$V_{DS} = 25 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 25 \text{ °C}$	-	-	10	μA
		$V_{DS} = 25 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 175 \text{ °C}$	-	-	500	μA
I _{GSS}	gate leakage current	V_{GS} = 15 V; V_{DS} = 0 V; T_j = 25 °C	-	10	100	nA
		$V_{GS} = -15 \text{ V}; V_{DS} = 0 \text{ V}; T_j = 25 \text{ °C}$	-	10	100	nA
R _{DSon}	drain-source on-state resistance	V_{GS} = 10 V; I_D = 25 A; T_j = 175 °C; see <u>Figure 9</u> ; see <u>Figure 10</u>	-	16.4	18.9	mΩ
		$V_{GS} = 5 \text{ V}; I_D = 25 \text{ A}; T_j = 25 \text{ °C};$ see Figure 9; see Figure 10	-	11.2	13.6	mΩ
		V_{GS} = 10 V; I_D = 25 A; T_j = 25 °C; see <u>Figure 9</u> ; see <u>Figure 10</u>	-	9.1	10.5	mΩ
Dynamic	characteristics					
Q _{G(tot)}	total gate charge	$I_D = 50 \text{ A}; V_{DS} = 15 \text{ V}; V_{GS} = 5 \text{ V};$	-	12	-	nC
Q_{GS}	gate-source charge	$T_j = 25 \text{ °C}; \text{ see } Figure 11$	-	4.5	-	nC
Q_{GD}	gate-drain charge		-	3.6	-	nC
C _{iss}	input capacitance	$V_{DS} = 25 \text{ V}; V_{GS} = 0 \text{ V}; f = 1 \text{ MHz};$	-	860	-	pF
C _{oss}	output capacitance	$T_j = 25 \text{ °C}; \text{ see } Figure 12$	-	330	-	pF
C _{rss}	reverse transfer capacitance		-	145	-	pF
t _{d(on)}	turn-on delay time	V_{DS} = 15 V; R_L = 0.6 Ω ; V_{GS} = 5 V;	-	15	25	ns
t _r	rise time	$R_{G(ext)} = 5.6 \ \Omega; T_j = 25 \ ^{\circ}C$	-	90	135	ns
t _{d(off)}	turn-off delay time		-	25	40	ns
t _f	fall time		-	25	40	ns
Source-d	Irain diode					
V_{SD}	source-drain voltage	I _S = 25 A; V _{GS} = 0 V; T _j = 25 °C; see <u>Figure 13</u>	-	0.95	1.2	V
t _{rr}	reverse recovery time	I_{S} = 10 A; dI_{S}/dt = -100 A/µs; V_{GS} = 0 V;	-	32	-	ns
Qr	recovered charge	V _{DS} = 25 V; T _j = 25 °C	-	20	-	nC
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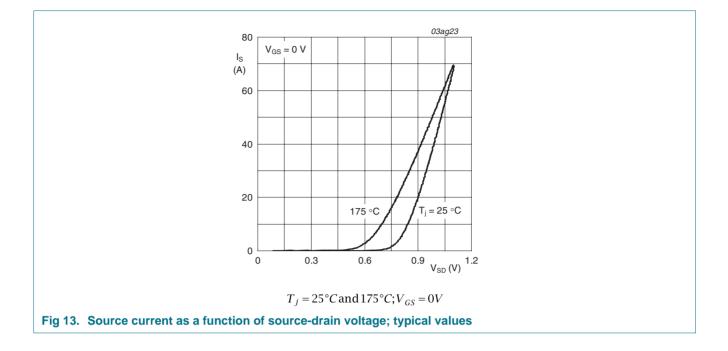
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7. Package outline

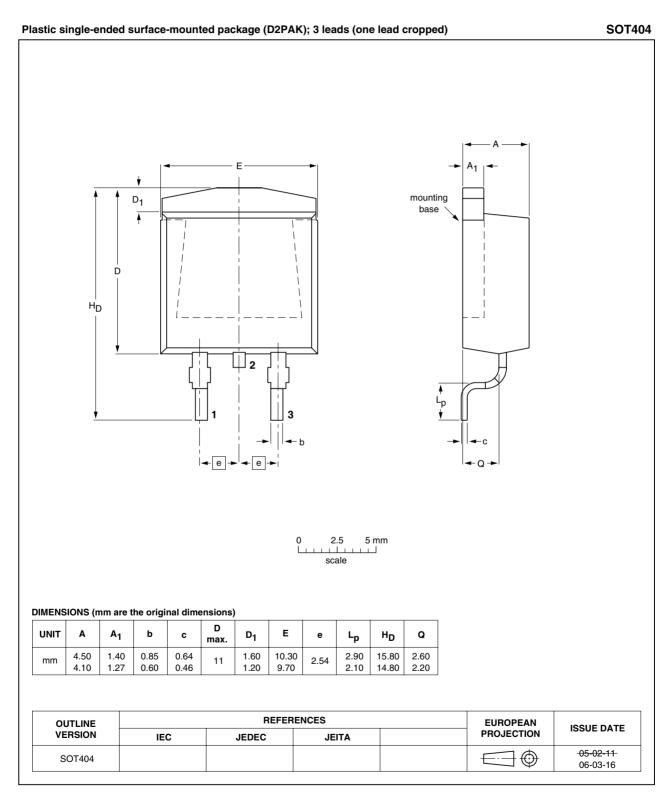


Fig 14. Package outline SOT404 (D2PAK)

8. Revision history

Table 7.Revision history				
Document ID	Release date	Data sheet status	Change notice	Supersedes
PHB66NQ03LT_7	20090130	Product data sheet	-	PHB_PHD66NQ03LT_6
Modifications:		of this data sheet has b of NXP Semiconductors	0	comply with the new identity
	 Legal texts 	have been adapted to t	he new company n	ame where appropriate.
PHB_PHD66NQ03LT_6 (9397 750 13429)	20040802	Product data sheet	-	PHP_PHB_PHD66NQ03LT_5
PHP_PHB_PHD66NQ03LT_5 (9397 750 13107)	20040415	Product data sheet	-	PHP_PHB_PHD66NQ03LT_4
PHP_PHB_PHD66NQ03LT_4 (9397 750 10158)	20020909	Product data sheet	-	PHP_PHB_PHD66NQ03LT_3
PHP_PHB_PHD66NQ03LT_3 (9397 750 09284)	20020312	Product data sheet	-	PHP_PHB_PHD66NQ03LT_2
PHP_PHB_PHD66NQ03LT_2 (9397 750 09119)	20011210	Product data sheet	-	PHP_PHB_PHD66NQ03LT_1
PHP_PHB_PHD66NQ03LT_1 (9397 750 08725)	20011012	Product data sheet	-	-

9. Legal information

9.1 Data sheet status

Document status [1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions"

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nexperia.com.

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